

# Readout of a dopant spin in the anisotropic quantum dot with a single magnetic ion

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Spin degree of freedom of defect centres in semiconductors is a desirable storage for quantum information thanks to relatively long coherence times caused by weak interaction with the crystal environment[1]. Owing to exchange interaction between the exciton and a dopant, a quantum dot embedding a single magnetic ion is a great platform for optical control of individual spin. In particular, a quantum dot provides strong and sharp optical transitions, which give experimental access to spin states of a specific magnetic ion. (Fig. 1)

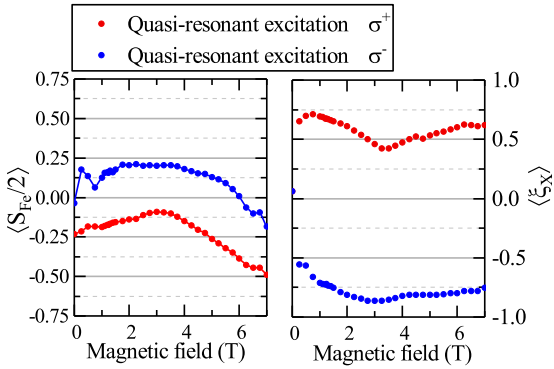


Figure 1: Spin orientations of exciton (a) and  $\text{Fe}^{2+}$  ion (b) under quasi-resonant excitation as a function of magnetic field, determined using proposed model. (from [2])

CdSe/ZnSe quantum dot containing a single  $\text{Fe}^{2+}$  ion. Both the resonant and non-resonant excitation regimes are explored resulting in a record high optical orientation efficiency of dopant spin in the former case. The proposed solutions can be easily expanded to any other system of quantum dots containing magnetic dopants.

We show, however, that physics of quantum dot excitons also complicate spin readout and optical spin manipulation in such a system. This is due to electron-hole exchange interaction in anisotropic quantum dots, which affects the polarization of the emission lines. One of the consequences is that the intensities of spectral lines in a single spectrum are not simply proportional to the population of various spin states of magnetic ion.

In order to provide a solution of the above problem, we present a method of extracting both the spin polarisation degree of a neutral exciton and magnetic dopant inside a semiconductor quantum dot in an external magnetic field. Our approach is experimentally verified on a system of

[1] M. Goryca et al. *Phys. Rev. Lett.* 113, 227202 (2014).

[2] A. Rodek et al. *arXiv:1903.02969*(2019)